

Order

Now



LM2733

SNVS209G - NOVEMBER 2002 - REVISED MAY 2019

LM2733 0.6- and 1.6-MHz Boost Converters With 40-V Internal FET Switch in SOT-23

Technical

Documents

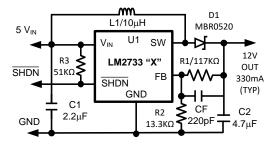
1 Features

- 40-V DMOS FET switch
- 1.6-MHz ("X"), 0.6 MHz ("Y") Switching frequency
- Low R_{DS(ON)} DMOS FET
- Switch current up to 1 A
- Wide input voltage 2.7 V to 14 V
- Low shutdown current (< 1 μA)
- 5-Pin SOT-23 package
- · Uses tiny capacitors and inductors
- Cycle-by-cycle current limiting
- Internally compensated

2 Applications

- White LED current source
- PDAs and palm-top computers
- Digital cameras
- Portable phones and games
- Local boost regulator

Typical Application Circuit



3 Description

Tools &

Software

The LM2733 switching regulators are current-mode boost converters operating fixed frequency of 1.6 MHz ("X" option) and 600 kHz ("Y" option).

Support &

Community

2.0

The use of SOT-23 package, made possible by the minimal power loss of the internal 1-A switch and use of small inductors and capacitors, results in the industry's highest power density. The 40-V internal switch makes these solutions perfect for boosting to voltages of 16 V or greater.

These parts have a logic-level shutdown pin that can be used to reduce quiescent current and extend battery life.

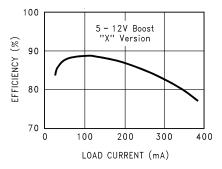
Protection is provided through cycle-by-cycle current limiting and thermal shutdown. Internal compensation simplifies design and reduces component count.

Device Information⁽¹⁾

Device information				
PART NUMBER	PACKAGE	BODY SIZE (NOM)		
LM2733	SOT-23 (5)	2.90 mm × 1.60 mm		

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Efficiency vs. Load Current



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

Table of Contents

1	Feat	tures 1
2	Арр	lications 1
3	Des	cription1
4	Rev	ision History 2
5	Pin	Configuration and Functions 3
6	Spe	cifications 3
	6.1	Absolute Maximum Ratings 3
	6.2	ESD Ratings 3
	6.3	Recommended Operating Conditions 4
	6.4	Thermal Information 4
	6.5	Electrical Characteristics 4
	6.6	Typical Characteristics 6
7	Deta	ailed Description 10
	7.1	Overview 10
	7.2	Functional Block Diagram 10

	7.3	Feature Description	10
	7.4	Device Functional Modes	11
8	Appl	ication and Implementation	12
	8.1	Application Information	12
	8.2	Typical Application	12
9		er Supply Recommendations	
10	Layo	out	18
	10.1	Layout Guidelines	18
	10.2	Layout Example	18
11	Devi	ice and Documentation Support	19
	11.1	Trademarks	19
	11.2	Electrostatic Discharge Caution	19
	11.3	Glossary	19
12		hanical, Packaging, and Orderable mation	19

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

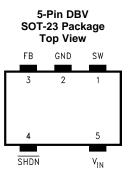
C	hanges from Revision F (December 2014) to Revision G	Page
•	Changed Typical Application Circuit image to correct rogue connector lines.	1
С	hanges from Revision E (April 2013) to Revision F	Page
•	Added Pin Configuration and Functions section, ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section	1
C	hanges from Revision D (April 2013) to Revision E	Page
•	Changed layout of National Semiconductor Data Sheet to TI format	11



www.ti.com



Pin Configuration and Functions 5



Pin Functions

PI	N	I/O	DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
SW	1	0	Drain of the internal FET switch.
GND	2	GND	Analog and power ground.
FB	3	1	Feedback point that connects to external resistive divider.
SHDN	4	I	Shutdown control input. Connect to V_{IN} if this feature is not used.
V _{IN}	5	I	Analog and power input.

Specifications 6

Absolute Maximum Ratings⁽¹⁾⁽²⁾ 6.1

	MIN	MAX	UNIT
Input supply voltage (VIN)	-0.4	14.5	V
FB pin voltage	-0.4	6	V
SW pin voltage	-0.4	40	V
SHDN pin voltage	-0.4	V _{IN} + 0.3	V
Power dissipation ⁽³⁾	Internally L	imited	
Lead temperature (soldering, 5 sec.)		300	°C
Storage temperature,T _{stg}	-65	150	°C

(1) Absolute Maximum Ratings indicate limits beyond which damage to the component may occur. Electrical specifications do not apply when operating the device outside of the limits set forth under the operating ratings which specify the intended range of operating conditions.

If Military/Aerospace specified devices are required, contact the Texas Instruments Sales Office/ Distributors for availability and (2)specifications.

The maximum power dissipation which can be safely dissipated for any application is a function of the maximum junction temperature, (3) T_J(MAX) = 125°C, the junction-to-ambient thermal resistance for the SOT-23 package, R_{0J-A} = 210°C/W, and the ambient temperature, T_A. The maximum allowable power dissipation at any ambient temperature for designs using this device can be calculated using the T_A . The maximum allowable power dissipation at any ambient temperature for designs using this device can be calculated using the P_A (MAX) = $\frac{T_J(MAX) - T_A}{\theta_{J-A}} = \frac{125 - T_A}{265}$ If power dissipation exceeds the maximum specified above, the internal thermal protect

265 If power dissipation exceeds the maximum specified above, the internal thermal protection circuitry protects the device by reducing the output voltage as required to maintain a safe junction temperature.

6.2 ESD Ratings

			VALUE	UNIT	
V	Electrostatia discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±2000	N	
V(ESD)	V _(ESD) Electrostatic discharge	Machine model	±200	v	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	MAX	UNIT
Input supply voltage (VIN)	2.7	14	V
SHDN pin voltage	0	V _{IN}	V
Junction temperature	-40	125	°C

6.4 Thermal Information

		LM2733	
	THERMAL METRIC ⁽¹⁾	DBV (SOT-23)	UNIT
		5 PINS	
$R_{ heta JA}$	Junction-to-ambient thermal resistance	210	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	122	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	38.4	°C/W
ΨJT	Junction-to-top characterization parameter	12.8	°C/W
Ψјв	Junction-to-board characterization parameter	37.5	°C/W
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics*SPRA953 application report.

6.5 Electrical Characteristics

Unless otherwise specified: $V_{IN} = 5 \text{ V}$, $V_{SHDN} = 5 \text{ V}$, $I_L = 0 \text{ A}$, $T_J = 25^{\circ}\text{C}$.

	PARAMETER	TEST CONDITIONS	MIN ⁽¹⁾	TYP ⁽²⁾	MAX ⁽¹⁾	UNIT
V _{IN}	Input voltage	$-40^{\circ}C \le T_{J} \le +125^{\circ}C$	2.7		14	V
I _{SW}	Switch current limit	See ⁽³⁾	1	1.5		А
R _{DS} (ON)	Switch ON resistance	I _{SW} = 100 mA		500	650	mΩ
		Device ON, $-40^{\circ}C \le T_{J} \le +125^{\circ}C$	1.5			
SHDN _{TH}	Shutdown threshold	Device OFF, −40°C ≤ T _J ≤ +125°C			0.50	V
		V _{SHDN} = 0		0		
I _{SHDN}	Shutdown pin bias current	V _{SHDN} = 5 V		0		μA
SHDN		$V_{SHDN} = 5 \text{ V}, -40^{\circ}\text{C} \le T_{J} \le +125^{\circ}\text{C}$			2	ы, с
N/	Foodbook pip reference voltage	V _{IN} = 3 V		1.230		V
V _{FB}	Feedback pin reference voltage	$V_{IN} = 3 \text{ V}, -40^{\circ}\text{C} \le \text{T}_{\text{J}} \le +125^{\circ}\text{C}$	1.205		1.255	v
I _{FB}	Feedback pin bias current	V _{FB} = 1.23 V		60		nA
		V _{SHDN} = 5 V, Switching "X"		2.1		
	Quiescent current	$V_{SHDN} = 5 V$, Switching "X", -40°C $\leq T_J \leq +125$ °C			3	mA
		V _{SHDN} = 5 V, Switching "Y"		1.1		
l _Q		$V_{SHDN} = 5 V$, Switching "Y", -40°C $\leq T_J \leq +125$ °C			2	
		V _{SHDN} = 5 V, Not Switching		400		
		$V_{SHDN} = 5 V$, Not Switching, -40°C $\leq T_J \leq +125$ °C			500	μA
		V _{SHDN} = 0		0.024	1	
$\Delta V_{FB} \overline{\Delta V_{IN}}$	FB voltage line regulation	2.7 V ≤ V _{IN} ≤ 14 V		0.02		%/V

(1) Limits are specified by testing, statistical correlation, or design.

(2) Typical values are derived from the mean value of a large quantity of samples tested during characterization and represent the most likely expected value of the parameter at room temperature.

(3) Switch current limit is dependent on duty cycle (see *Typical Characteristics*). Limits shown are for duty cycles \leq 50%.

4 Submit Documentation Feedback

Downloaded From Oneyac.com



Electrical Characteristics (continued)

Unless otherwise specified: V_{IN} = 5 V, V_{SHDN} = 5 V, I_L = 0 A, T_J = 25^{\circ}C.

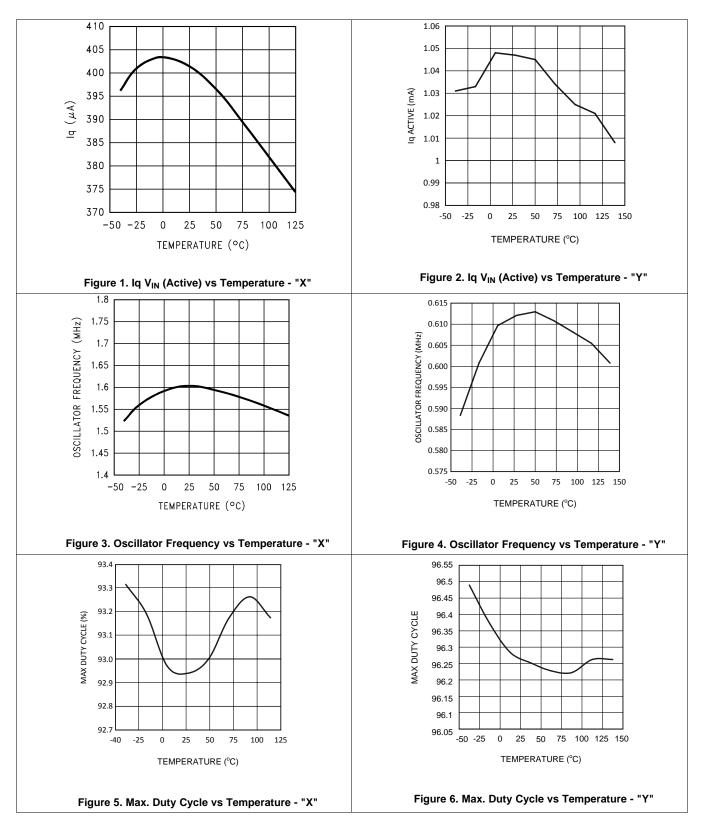
	PARAMETER	TEST CONDITIONS	MIN ⁽¹⁾	TYP ⁽²⁾	MAX ⁽¹⁾	UNIT
		"X" Option		1.6		
E	Switching froquency	"X" Option, −40°C ≤ T_J ≤ +125°C	1.15		1.85	MHz
F _{SW}	Switching frequency	"Y" Option		0.60		
		"Y" Option, $-40^{\circ}C \le T_{J} \le +125^{\circ}C$	0.40		0.8	
		"X" Option		93%		
D		"X" Option, $-40^{\circ}C \le T_{J} \le +125^{\circ}C$	87%			
D _{MAX}	Maximum duty cycle	"Y" Option		96%		
		"Y" Option, $-40^{\circ}C \le T_{J} \le +125^{\circ}C$	93%			
IL	Switch leakage	Not Switching $V_{SW} = 5 V$			1	μA

LM2733 SNVS209G – NOVEMBER 2002 – REVISED MAY 2019 TEXAS INSTRUMENTS

www.ti.com

6.6 Typical Characteristics

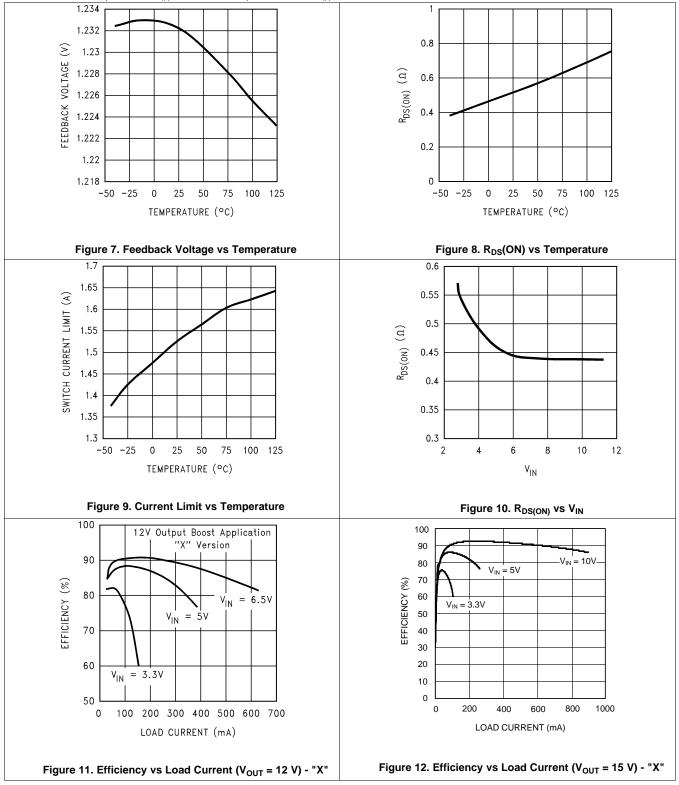
Unless otherwise specified: $V_{IN} = 5 V$, SHDN pin is tied to V_{IN} .





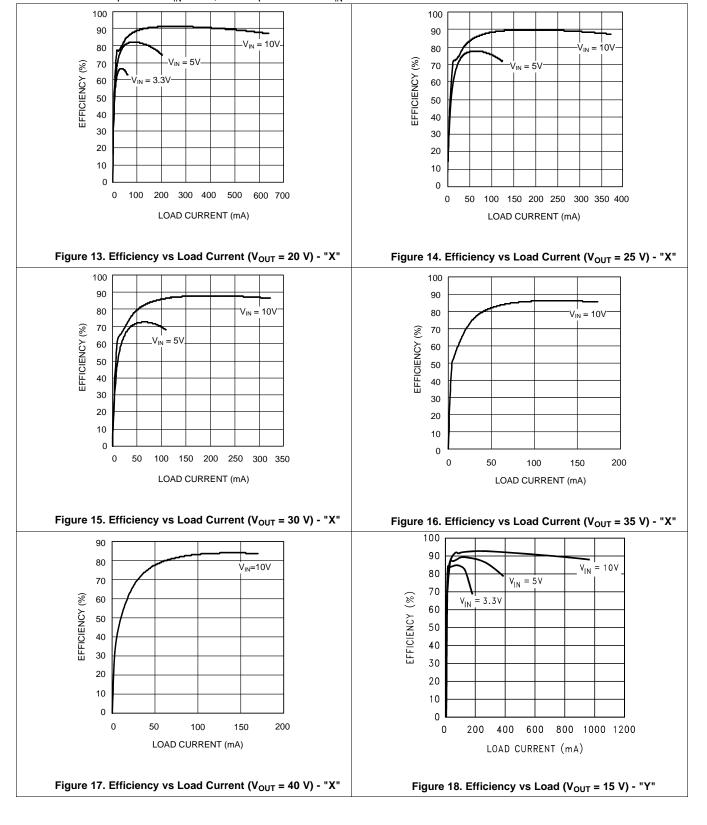
Typical Characteristics (continued)

Unless otherwise specified: $V_{IN} = 5 \text{ V}$, SHDN pin is tied to V_{IN} .



Typical Characteristics (continued)

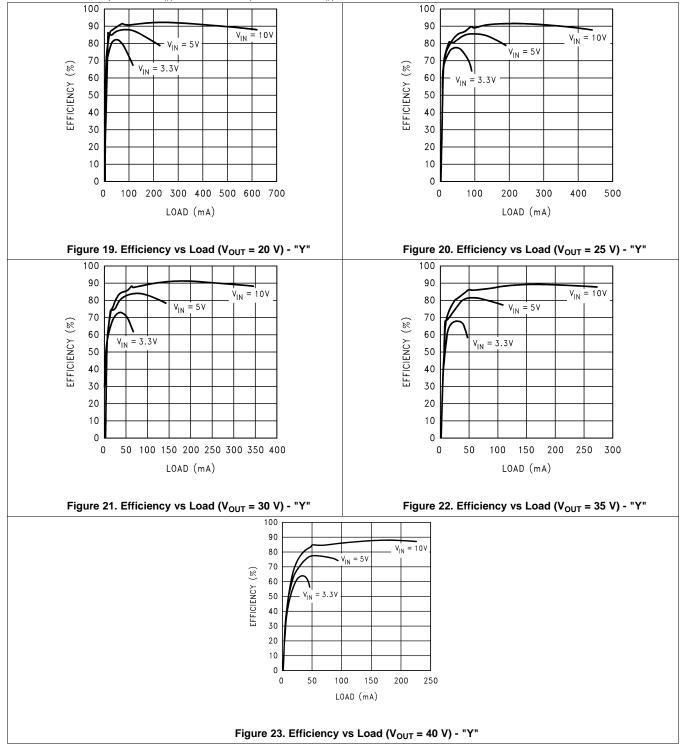
Unless otherwise specified: $V_{IN} = 5 \text{ V}$, \overline{SHDN} pin is tied to V_{IN} .





Typical Characteristics (continued)

Unless otherwise specified: $V_{IN} = 5 \text{ V}$, SHDN pin is tied to V_{IN} .



Downloaded From Oneyac.com

TEXAS INSTRUMENTS

www.ti.com

7 Detailed Description

7.1 Overview

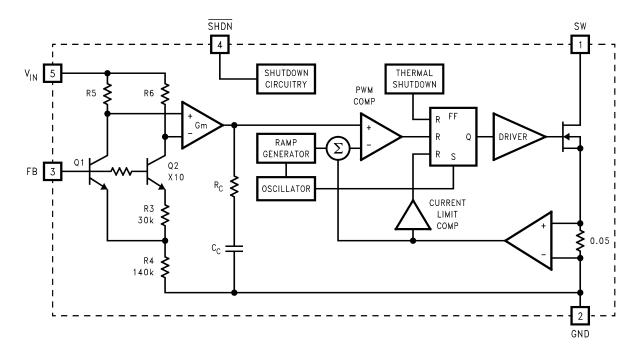
The LM2733 device is a switching converter IC that operates at a fixed frequency (0.6 or 1.6 MHz) using currentmode control for fast transient response over a wide input voltage range and incorporate pulse-by-pulse current limiting protection. Because this is current mode control, a 50 m Ω sense resistor in series with the switch FET is used to provide a voltage (which is proportional to the FET current) to both the input of the pulse width modulation (PWM) comparator and the current limit amplifier.

At the beginning of each cycle, the S-R latch turns on the FET. As the current through the FET increases, a voltage (proportional to this current) is summed with the ramp coming from the ramp generator and then fed into the input of the PWM comparator. When this voltage exceeds the voltage on the other input (coming from the Gm amplifier), the latch resets and turns the FET off. Since the signal coming from the Gm amplifier is derived from the feedback (which samples the voltage at the output), the action of the PWM comparator constantly sets the correct peak current through the FET to keep the output volatge in regulation.

Q1 and Q2 along with R3 - R6 form a bandgap voltage reference used by the IC to hold the output in regulation. The currents flowing through Q1 and Q2 will be equal, and the feedback loop will adjust the regulated output to maintain this. Because of this, the regulated output is always maintained at a voltage level equal to the voltage at the FB node "multiplied up" by the ratio of the output resistive divider.

The current limit comparator feeds directly into the flip-flop, that drives the switch FET. If the FET current reaches the limit threshold, the FET is turned off and the cycle terminated until the next clock pulse. The current limit input terminates the pulse regardless of the status of the output of the PWM comparator.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Switching Frequency

The LM2733 device is provided with two switching frequencies: the "X" version is typically 1.6 MHz, while the "Y" version is typically 600 kHz. The best frequency for a specific application must be determined based on the tradeoffs involved. See *Switching Frequency* in the *Detailed Design Procedure* section.



7.4 Device Functional Modes

7.4.1 Shutdown Pin Operation

The device is turned off by pulling the shutdown pin low. If this function is not going to be used, tie the pin directly to V_{IN} . If the SHDN function is needed, a pullup resistor must be used to V_{IN} (approximately 50 k to 100 $k\Omega$ recommended). The SHDN pin must not be left unterminated.



TEXAS INSTRUMENTS

www.ti.com

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The LM2733 device is a high frequency switching boost regulator that offers small size and high power conversion efficiency. The "X" version of the part operates at 1.6 MHz switching frequency and the "Y" version at 600 kHz.

The LM2733 device targets applications with high output voltages and uses a high voltage FET allowing switch currents up to 1 A. The LM2731 device is similar to the LM2733 device but has a lower voltage FET allowing switch currents up to 1.8 A.

8.2 Typical Application

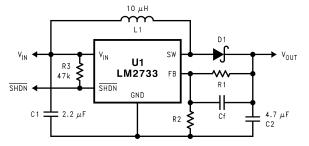


Figure 24. Basic Application Circuit

8.2.1 Design Requirements

Table 1. Circuit Configuration	าร
--------------------------------	----

	LM2733-X	LM2733-X	LM2733-Y HIGH VOLTAGE 30 V 110 mA typical			
COMPONENT	LOW VOLTAGE 5-12 V 330 mA typical	HIGH VOLTAGE 20 V 170 mA typical				
R1	117 K	205 K	309 K			
R2	13.3 K	13.3 K	13.3 K			
Cf	220 pF	120 pF	82 pF			
D1	MBR0520	MBR0530	MBR0540			

8.2.2 Detailed Design Procedure

8.2.2.1 Selecting the External Capacitors

The best capacitors for use with the LM2733 device are multi-layer ceramic capacitors. They have the lowest ESR (equivalent series resistance) and highest resonance frequency which makes them optimum for use with high frequency switching converters.

When selecting a ceramic capacitor, use only X5R and X7R dielectric types. Other types such as Z5U and Y5F have such severe loss of capacitance due to effects of temperature variation and applied voltage, they may provide as little as 20% of rated capacitance in many typical applications. Always consult capacitor manufacturer's data curves before selecting a capacitor. High-quality ceramic capacitors can be obtained from Taiyo-Yuden, AVX, and Murata.



8.2.2.2 Selecting the Output Capacitor

A single ceramic capacitor of value 4.7 μ F to 10 μ F provides sufficient output capacitance for most applications. For output voltages below 10 V, a 10- μ F capacitance is required. If larger amounts of capacitance are desired for improved line support and transient response, tantalum capacitors can be used in parallel with the ceramics. Aluminum electrolytics with ultra-low ESR such as Sanyo Oscon can be used, but are usually prohibitively expensive. Typical AI electrolytic capacitors are not suitable for switching frequencies above 500 kHz due to significant ringing and temperature rise due to self-heating from ripple current. An output capacitor with excessive ESR can also reduce phase margin and cause instability.

8.2.2.3 Selecting the Input Capacitor

An input capacitor is required to serve as an energy reservoir for the current which must flow into the coil each time the switch turns ON. This capacitor must have extremely low ESR, so ceramic is the best choice. The recommends a nominal value of 2.2 μ F, but larger values can be used. Because this capacitor reduces the amount of voltage ripple detected at the input pin, it also reduces the amount of EMI passed back along that line to other circuitry.

8.2.2.4 Feedforward Compensation

Although internally compensated, the feedforward capacitor Cf is required for stability (see Figure 24). Adding this capacitor puts a zero in the loop response of the converter. Without it, the regulator loop can oscillate. The recommended frequency for the zero fz is approximately 8 kHz. Cf can be calculated using the formula:

$$Cf = 1 / (2 X \pi X R1 X fz)$$

8.2.2.5 Selecting Diodes

The external diode used in the typical application should be a Schottky diode. If the switch voltage is less than 15 V, a 20-V diode such as the MBR0520 is recommended. If the switch voltage is between 15 V and 25 V, TI recommends a 30-V diode such as the MBR0530. If the switch voltage exceeds 25 V, a 40-V diode such as the MBR0540 should be used.

The MBR05XX series of diodes are designed to handle a maximum average current of 0.5 A. For applications exceeding 0.5 A average but less than 1 A, a Microsemi UPS5817 can be used.

8.2.2.6 Setting the Output Voltage

The output voltage is set using the external resistors R1 and R2 (see Figure 24). A value of approximately 13.3 $k\Omega$ is recommended for R2 to establish a divider current of approximately 92 μ A. R1 is calculated using the formula:

 $R1 = R2 X (V_{OUT}/1.23 - 1)$

(2)

(1)

8.2.2.7 Switching Frequency

The device options provide for two fixed frequency operating conditions 1.6 MHz, and 600 kHz. Chose the operating frequency required noting the following trade-offs:

Higher switching frequency means the inductors and capacitors can be made smaller and cheaper for a given output voltage and current. The down side is that efficiency is slightly lower because the fixed switching losses occur more frequently and become a larger percentage of total power loss. EMI is typically worse at higher switching frequencies because more EMI energy will be seen in the higher frequency spectrum where most circuits are more sensitive to such interference.

8.2.2.8 Duty Cycle

The maximum duty cycle of the switching regulator determines the maximum boost ratio of output-to-input voltage that the converter can attain in continuous mode of operation. The duty cycle for a given boost application is defined as:

Duty Cycle =
$$\frac{V_{OUT} + V_{DIODE} - V_{IN}}{V_{OUT} + V_{DIODE} - V_{SW}}$$

This applies for continuous mode operation.

13

Submit Documentation Feedback

The equation shown for calculating duty cycle incorporates terms for the FET switch voltage and diode forward voltage. The actual duty cycle measured in operation will also be affected slightly by other power losses in the circuit such as wire losses in the inductor, switching losses, and capacitor ripple current losses from self-heating. Therefore, the actual (effective) duty cycle measured may be slightly higher than calculated to compensate for these power losses. A good approximation for effective duty cycle is :

DC (eff) =
$$(1 - \text{Efficiency x} (V_{IN}/V_{OUT}))$$

Where the efficiency can be approximated from the curves provided.

8.2.2.9 Inductance Value

The first question we are usually asked is: "How small can I make the inductor?" (because they are the largest sized component and usually the most costly). The answer is not simple and involves tradeoffs in performance. Larger inductors mean less inductor ripple current, which typically means less output voltage ripple (for a given size of output capacitor). Larger inductors also mean more load power can be delivered because the energy stored during each switching cycle is:

 $E = L/2 X (lp)^2$

Where "lp" is the peak inductor current. An important point to observe is that the LM2733 device will limit its switch current based on peak current. This means that since lp (maximum) is fixed, increasing L will increase the maximum amount of power available to the load. Conversely, using too little inductance may limit the amount of load current which can be drawn from the output.

Best performance is usually obtained when the converter is operated in "continuous" mode at the load current range of interest, typically giving better load regulation and less output ripple. Continuous operation is defined as not allowing the inductor current to drop to zero during the cycle. It should be noted that all boost converters shift over to discontinuous operation as the output load is reduced far enough, but a larger inductor stays "continuous" over a wider load current range.

To better understand these tradeoffs, a typical application circuit (5V to 12V boost with a 10 μ H inductor) will be analyzed. We will assume:

$$V_{IN} = 5 \text{ V}, V_{OUT} = 12 \text{ V}, V_{DIODE} = 0.5 \text{ V}, V_{SW} = 0.5 \text{ V}$$

Since the frequency is 1.6 MHz (nominal), the period is approximately 0.625 μ s. The duty cycle will be 62.5%, which means the ON time of the switch is 0.390 μ s. It should be noted that when the switch is ON, the voltage across the inductor is approximately 4.5 V.

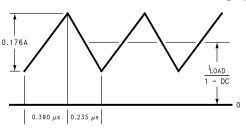
$$V = L (di/dt)$$

(6)

We can then calculate the di/dt rate of the inductor which is found to be 0.45 A/µs during the ON time. Using these facts, we can then show what the inductor current will look like during operation:

Figure 25. 10-µH Inductor Current, 5-V – 12-V Boost (LM2733X)

During the 0.390 µs ON time, the inductor current ramps up 0.176 A and ramps down an equal amount during the OFF time. This is defined as the inductor "ripple current". It can also be seen that if the load current drops to about 33 mA, the inductor current will begin touching the zero axis which means it will be in discontinuous mode. A similar analysis can be performed on any boost converter, to make sure the ripple current is reasonable and continuous operation will be maintained at the typical load current values.



www.ti.com

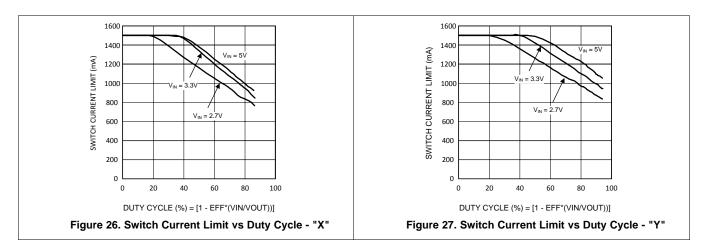
(5)

(4)



8.2.2.10 Maximum Switch Current

The maximum FET swtch current available before the current limiter cuts in is dependent on duty cycle of the application. This is illustrated in the graphs below which show both the typical and specified values of switch current for both the "X" and "Y" versions as a function of effective (actual) duty cycle:



8.2.2.11 Calculating Load Current

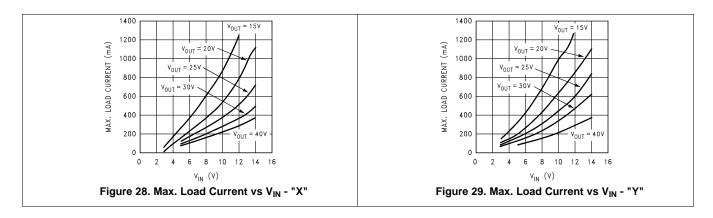
As shown in the figure which depicts inductor current, the load current is related to the average inductor current by the relation:

$I_{LOAD} = I_{IND}(AVG) \times (1 - DC)$	(7)
Where "DC" is the duty cycle of the application. The switch current can be found by:	
$I_{SW} = I_{IND}(AVG) + \frac{1}{2} (I_{RIPPLE})$	(8)
Inductor ripple current is dependent on inductance, duty cycle, input voltage and frequency:	
$I_{RIPPLE} = DC \times (V_{IN}-V_{SW}) / (f \times L)$	(9)

combining all terms, we can develop an expression which allows the maximum available load current to be calculated:

 $I_{\text{LOAD}}(\text{max}) = (1 - \text{DC}) \times (I_{\text{SW}}(\text{max}) - \frac{\text{DC} (V_{\text{IN}} - V_{\text{SW}}))}{2\text{fL}}$

The equation shown to calculate maximum load current takes into account the losses in the inductor or turn-OFF switching losses of the FET and diode. For actual load current in typical applications, we took bench data for various input and output voltages for both the "X" and "Y" versions of the LM2733 device and displayed the maximum load current available for a typical device in graph form:



(10)

V = L X dI/dt, $L = V X (dt/dI) = 4.8 (0.524 \mu/1) = 2.5 \mu H$

8.2.2.12 Design Parameters V_{SW} and I_{SW}

The value of the FET "ON" voltage (referred to as V_{SW} in the equations) is dependent on load current. A good approximation can be obtained by multiplying the "ON Resistance" of the FET times the average inductor current.

FET on resistance increases at V_{IN} values below 5 V, since the internal N-FET has less gate voltage in this input voltage range (see *Typical Characteristics*). Above $V_{IN} = 5 V$, the FET gate voltage is internally clamped to 5 V.

The maximum peak switch current the device can deliver is dependent on duty cycle. The minimum value is specified to be > 1 A at duty cycle below 50%. For higher duty cycles, see *Typical Characteristics*.

8.2.2.13 Thermal Considerations

At higher duty cycles, the increased ON time of the FET means the maximum output current will be determined by power dissipation within the LM2733 FET switch. The switch power dissipation from ON-state conduction is calculated by:

$$P_{(SW)} = DC \times I_{IND} (AVE)^2 \times R_{DS} ON$$

There will be some switching losses as well, so some derating needs to be applied when calculating IC power dissipation.

8.2.2.14 Minimum Inductance

In some applications where the maximum load current is relatively small, it may be advantageous to use the smallest possible inductance value for cost and size savings. The converter will operate in discontinuous mode in such a case.

The minimum inductance should be selected such that the inductor (switch) current peak on each cycle does not reach the 1-A current limit maximum. To understand how to do this, an example will be presented.

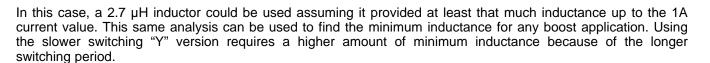
In the example, the LM2733X will be used (nominal switching frequency 1.6 MHz, minimum switching frequency 1.15 MHz). This means the maximum cycle period is the reciprocal of the minimum frequency:

 $T_{ON(max)} = 1/1.15M = 0.870 \ \mu s$

We will assume the input voltage is 5 V, $V_{OUT} = 12$ V, $V_{SW} = 0.2$ V, $V_{DIODF} = 0.3$ V. The duty cycle is:

Duty Cycle = 60.3%

Therefore, the maximum switch ON time is 0.524 µs. An inductor should be selected with enough inductance to prevent the switch current from reaching 1A in the 0.524 µs ON time interval (see below):



8.2.2.15 Inductor Suppliers

16

Some of the recommended suppliers of inductors for this product include, but not limited to are Sumida, Coilcraft, Panasonic, TDK and Murata. When selecting an inductor, make certain that the continuous current rating is high enough to avoid saturation at peak currents. A suitable core type must be used to minimize core (switching) losses, and wire power losses must be considered when selecting the current rating.

Downloaded From Oneyac.com

Product Folder Links: LM2733

STRUMENTS

www.ti.com

(11)

(12)

(13)

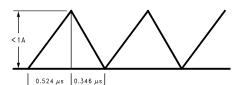
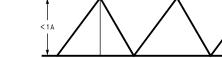


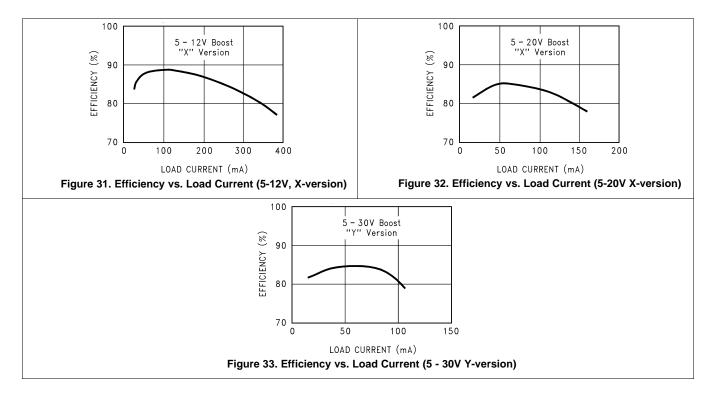
Figure 30. Discontinuous Design, 5V–12V Boost (LM2733X)



The voltage across the inductor during ON time is 4.8V. Minimum inductance value is found by:



8.2.3 Application Curves





9 Power Supply Recommendations

The device input voltage range is 2.7 V to 14 V.

The voltage on the shutdown pin should not exceed the voltage on the VIN pin. For applications that do not require a shutdown function the shutdown pin may be connected to the VIN pin. In this case a 47-K Ω resistor is recommended to be connected between these pins.

10 Layout

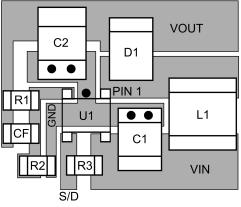
10.1 Layout Guidelines

High frequency switching regulators require very careful layout of components in order to get stable operation and low noise. All components must be as close as possible to the LM2733 device. It is recommended that a 4-layer PCB be used so that internal ground planes are available.

Some additional guidelines to be observed:

- 1. Keep the path between L1, D1, and C2 extremely short. Parasitic trace inductance in series with D1 and C2 will increase noise and ringing.
- 2. The feedback components R1, R2 and CF must be kept close to the FB pin of U1 to prevent noise injection on the FB pin trace.
- 3. If internal ground planes are available (recommended) use vias to connect directly to ground at pin 2 of U1, as well as the negative sides of capacitors C1 and C2.

10.2 Layout Example



• VIAS TO GROUND PLANE

Figure 34. Recommended PCB Component Layout



11 Device and Documentation Support

11.1 Trademarks

All trademarks are the property of their respective owners.

11.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
	(.)		Ū			(=)	(6)	(0)		(,	
LM2733XMF	LIFEBUY	SOT-23	DBV	5	1000	Non-RoHS & Green	Call TI	Level-1-260C-UNLIM	-40 to 125	S52A	
LM2733XMF/NOPB	ACTIVE	SOT-23	DBV	5	1000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	S52A	Samples
LM2733XMFX/NOPB	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	S52A	Samples
LM2733YMF	LIFEBUY	SOT-23	DBV	5	1000	Non-RoHS & Green	Call TI	Level-1-260C-UNLIM	-40 to 125	S52B	
LM2733YMF/NOPB	ACTIVE	SOT-23	DBV	5	1000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	S52B	Samples
LM2733YMFX/NOPB	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	S52B	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



19-Sep-2023

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM2733XMF	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM2733XMF/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM2733XMFX/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM2733YMF	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM2733YMF/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM2733YMFX/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

Pack Materials-Page 1



PACKAGE MATERIALS INFORMATION

9-Aug-2022



Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM2733XMF	SOT-23	DBV	5	1000	210.0	185.0	35.0
LM2733XMF/NOPB	SOT-23	DBV	5	1000	210.0	185.0	35.0
LM2733XMFX/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LM2733YMF	SOT-23	DBV	5	1000	210.0	185.0	35.0
LM2733YMF/NOPB	SOT-23	DBV	5	1000	210.0	185.0	35.0
LM2733YMFX/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0

Pack Materials-Page 2

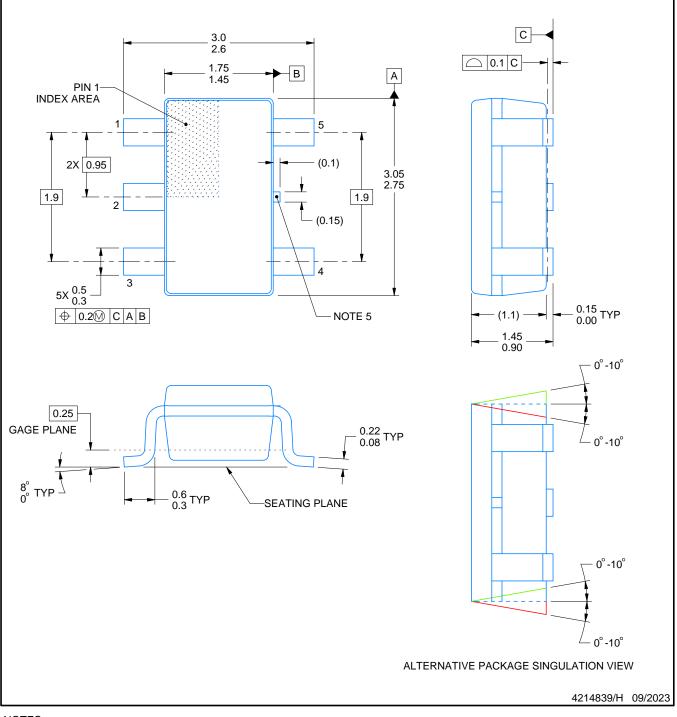
DBV0005A



PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. Refernce JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.

DBV0005A

EXAMPLE BOARD LAYOUT

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

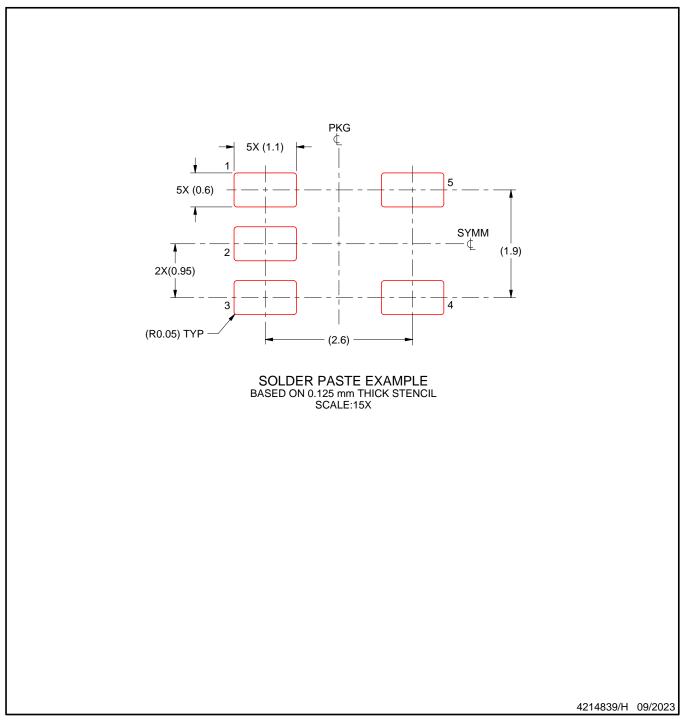


DBV0005A

EXAMPLE STENCIL DESIGN

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2023, Texas Instruments Incorporated 单击下面可查看定价,库存,交付和生命周期等信息

>>TI(德州仪器)